# NSN 5962-01-244-8514

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# Body Length:

2.010 inches

#### **Body Width:**

0.900 inches

## **Body Height:**

0.260 inches

## **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-46.0/+110.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# **End Application:**

7010-01-085-4310 computer termin

#### **Features Provided:**

Hermetically sealed and electrostatic sensitive and high reliability

#### Inclosure Material:

Ceramic

## **Inclosure Configuration:**

Dual-in-line

# Output Logic Form:

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

19 input

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

# **Time Rating Per Chacteristic:**

150.00 nanoseconds propagation delay time, low to high level output and 150.00 nanoseconds propagation delay time, high to low level output

# Memory Device Type:

Ram

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

40 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

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